

HA16341NT/FP, HA16342NT/FP

Redundant Secondary Switching Power Supply Controller

HITACHI

ADE-204-035C (Z)

Rev.3
Apr. 2001

Description

The HA16341NT/FP and the HA16342NT/FP are switching regulator control ICs for the off-line converters of redundant power supplies.

The HA16342NT/FP is reverse current detection less version of the HA16341NT/FP.

The HA16341NT/FP have the functions of current sharing and hot swap control for redundancy. These functions enable high efficiency and high reliability for switching power supplies.

Combination the HA16341 with the HA16141 is suitable for the redundant AC to DC converters.

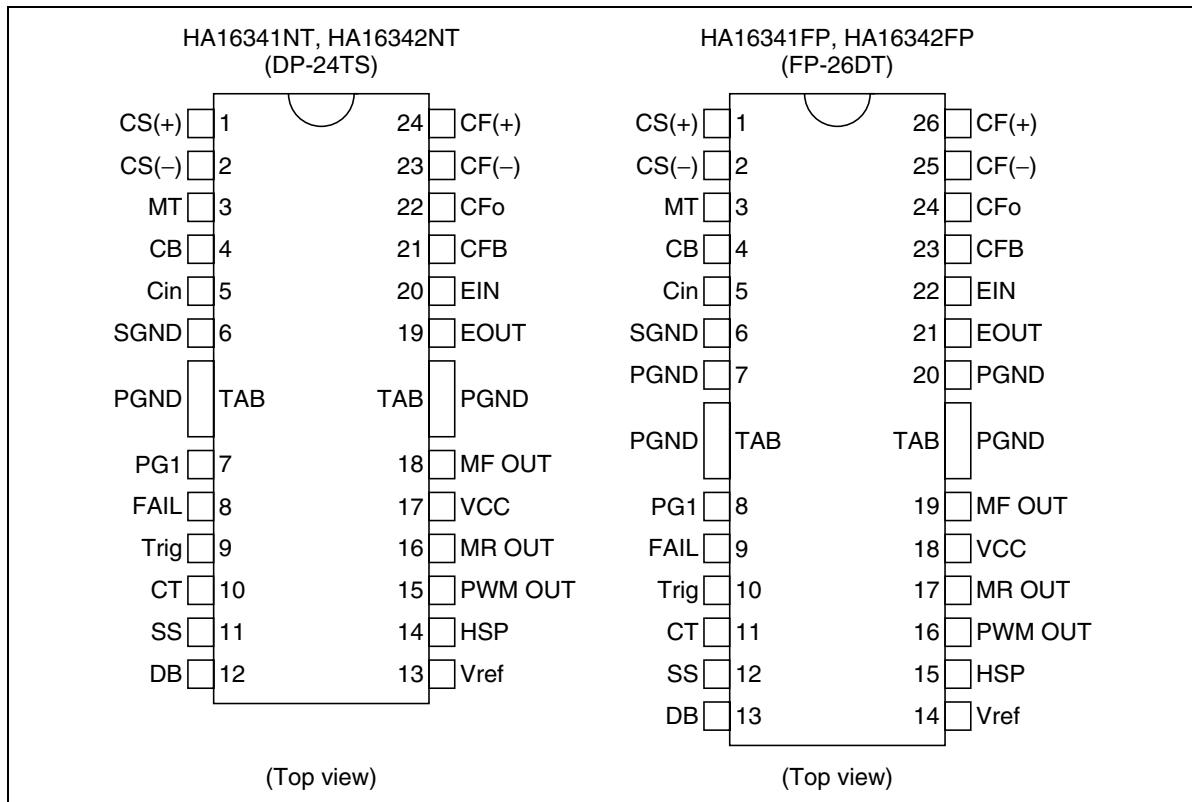
Features

- Secondary-side synchronous rectification control
- Main switching controller
- Dead-time adjustment for synchronous rectification MOS
- Current share function with line resistance compensation
- Hot swap power MOS FET control
- Remote on/off function, FAIL output function
- Synchronized switching with primary side
- Soft start function
- Maximum duty adjustment
- Overcurrent limiting, overcurrent shutdown functions
- Reverse current detection (only the HA16341NT/FP)
- Light load detection
- OVP function
- VCC pin UVL function

Ordering Information

| Type No. | Package |
|-----------|---------|
| HA16341NT | DP-24TS |
| HA16342NT | |
| HA16341FP | FP-26DT |
| HA16342FP | |

Pin Arrangement

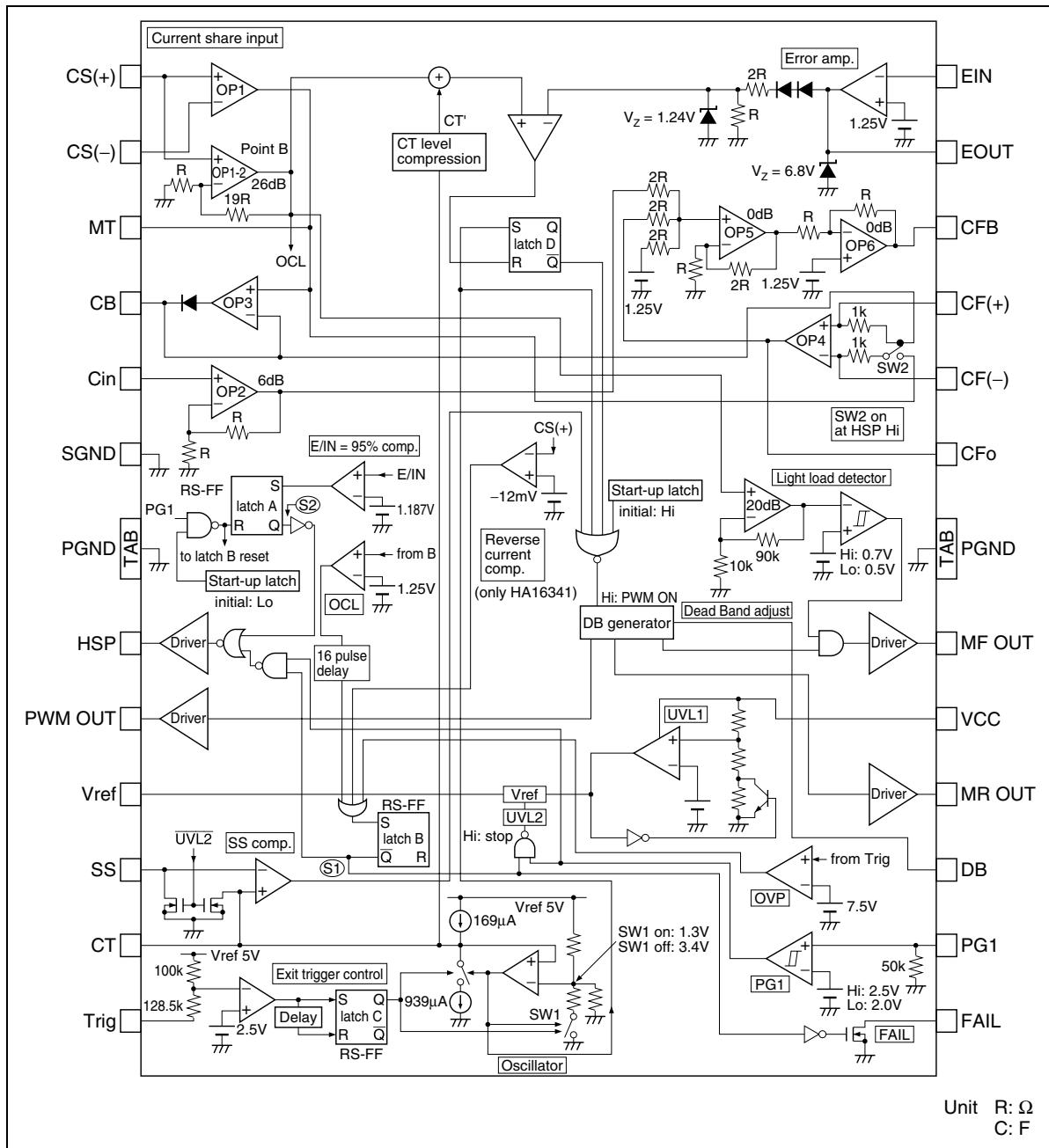


Pin Functions

Pin No.

| DP-24TS | FP-26DT | Symbol | Pin Name |
|---------|------------|---------|--|
| 1 | 1 | CS(+) | Current sense amp input (+) |
| 2 | 2 | CS(-) | Current sense amp input (-) |
| 3 | 3 | MT | Current sense amp output |
| 4 | 4 | CB | Current bus output |
| 5 | 5 | Cin | Line resistance compensation input |
| 6 | 6 | SGND | Signal ground |
| 7 | 8 | PG1 | Remote on/off |
| 8 | 9 | FAIL | FAIL output (open-drain) |
| 9 | 10 | Trig | External synchronization input |
| 10 | 11 | CT | Timing capacitance |
| 11 | 12 | SS | Soft start |
| 12 | 13 | DB | Dead band |
| 13 | 14 | Vref | Vref (5 V) |
| 14 | 15 | HSP | Hot swap output |
| 15 | 16 | PWM OUT | PWM output |
| 16 | 17 | MR OUT | MR output |
| 17 | 18 | VCC | Power supply voltage |
| 18 | 19 | MF OUT | MF output |
| 19 | 21 | EOUT | Error amp output |
| 20 | 22 | EIN | Error amp input |
| 21 | 23 | CFB | Current share feedback output |
| 22 | 24 | CFo | Current share differential amp output |
| 23 | 25 | CF(-) | Current share differential amp input (-) |
| 24 | 26 | CF(+) | Current share differential amp input (+) |
| TAB | TAB, 7, 20 | PGND | Power ground |

Block Diagram



Absolute Maximum Ratings

(Ta = 25°C)

| Item | Symbol | Rating | Unit | Note |
|--------------------------|------------|-------------------------|------|------------------------|
| Supply Voltage | VCC | 18 | V | |
| DC output current1 | Io1 | ±0.1 | A | PWM OUT * ¹ |
| Peak output current1 | Iopeak1 | ±1.0 | A | PWM OUT * ² |
| DC output current2 | Io2 | ±0.2 | A | MF OUT * ¹ |
| Peak output current2 | Iopeak2 | ±2.0 | A | MF OUT * ² |
| DC output current3 | Io3 | ±0.1 | A | MR OUT * ¹ |
| Peak output current3 | Iopeak3 | ±1.0 | A | MR OUT * ² |
| DC output current4 | Io4 | -5 | mA | CB OUT |
| DC output current5 | Io5 | ±500 | µA | CFB OUT |
| DC output current6 | Io6 | 20 | mA | FAIL OUT |
| DC output current7 | Io7 | -5.0 | mA | Vref OUT |
| Peak output current4 | Iopeak4 | 0.5 | A | HSP sink |
| DC output current8 | Io8 | ±500 | µA | MT OUT |
| DC output current9 | Io9 | ±500 | µA | CFo OUT |
| DC output current10 | Io10 | 6 | mA | EOUT sink |
| TRIG terminal voltage | Vtrigmax | -1.5 to V _{CC} | V | |
| CT terminal voltage | VCTmax | -0.3 to Vref | V | |
| Vref terminal voltage | Vrefmax | -0.3 to Vref | V | |
| SS terminal voltage | Vssmax | -0.3 to Vref | V | |
| EIN terminal voltage | VEINmax | -0.3 to Vref | V | |
| EOUT terminal voltage | VEOUTmax | -0.3 to V _{CC} | V | |
| PG1 terminal voltage | VPG1max | -0.3 to Vref | V | |
| FAIL terminal voltage | VFAILmax | -0.3 to V _{CC} | V | |
| PWM OUT terminal voltage | VoPWMmax | -0.3 to V _{CC} | V | |
| MR OUT terminal voltage | VoMRmax | -0.3 to V _{CC} | V | |
| MF OUT terminal voltage | VoMFmax | -0.3 to V _{CC} | V | |
| HSP terminal voltage | VoHSPmax | -0.3 to V _{CC} | V | |
| CFB terminal voltage | VCFBmax | -0.3 to Vref | V | |
| CS(+) terminal voltage | VCS(+)-max | -0.3 to Vref | V | |
| CS(-) terminal voltage | VCS(-)-max | -0.3 to Vref | V | |
| MT terminal voltage | VMTmax | -0.3 to Vref | V | |
| Cin terminal voltage | VCinmax | -0.3 to Vref | V | |

Notes: 1. V_{DS} = 10 V max. Therefore test condition must be V_{OH} = V_{CC} - 10 V or over , V_{OL} = 10 V or under.2. V_{DS} = 10 V max. Pulse duration ≤ 10 ms

Absolute Maximum Ratings (cont.)

(Ta = 25°C)

| Item | Symbol | Rating | Unit | Note |
|---------------------------|------------------|--------------|------|------|
| CF(+) terminal voltage | VCF(+)-max | -0.3 to Vref | V | |
| CF(-) terminal voltage | VCF(-)-max | -0.3 to Vref | V | |
| CFo terminal voltage | VCFomax | -0.3 to Vref | V | |
| CB terminal voltage | VCBmax | -0.3 to Vref | V | |
| DB terminal voltage | VDBmax | -0.3 to Vref | V | |
| Maximum power dissipation | P _T | 4.17 | W | 1 |
| Operating temperature | T _{opr} | -40 to +105 | °C | |
| Storage temperature | T _{stg} | -55 to +150 | °C | |
| Junction temperature | T _j | 150 | °C | |

Note: 1. This is allowable value up to Ta = 25°C.

Derate by $\theta_{j-a} = 30^{\circ}\text{C}/\text{W}$ above that temperature.

$\theta_{j-a} = 30^{\circ}\text{C}/\text{W}$ is the case that HA16341NT is mounted on 30% wiring density glass epoxy board (105 mm × 76.2 mm × 1.6 mmt) and HA16341FP is mounted on a board which thermal resistance is 23°C/W because of $\theta_{j\text{-pin}} (\text{SOP}) = 7^{\circ}\text{C}/\text{W}$ typ.

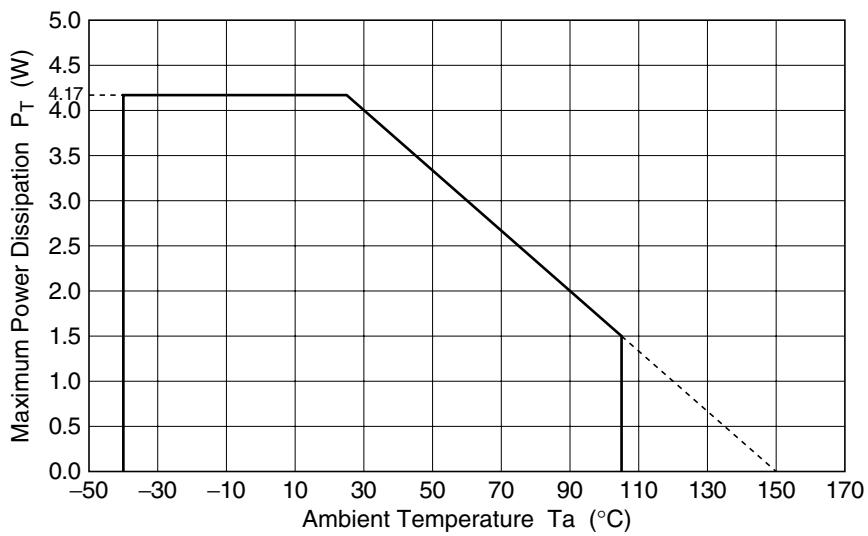


Figure 1 Derating Curve

Electrical Characteristics

($T_a = 25^\circ\text{C}$, $V_{CC} = 12\text{V}$, $\text{PG1} = 3\text{V}$, $\text{Vtrig} = 0\text{V}$, $\text{VCS}(+) = 0\text{V}$, $\text{VCin} = 0\text{V}$, $\text{CCT} = 330\text{pF}$, $\text{GvOP1} = 26\text{dB}$, $\text{GvOP4} = 40\text{dB}$, $\text{RDB} = 1.8\text{k}\Omega$)

- Current share

| Item | Symbol | Min | Typ | Max | Unit | Test Conditions | Note |
|---|----------|-------|------|-------|------------------|--|------|
| CB output Hi voltage | VCBH | 2.5 | — | — | V | $I_{osource} = 300\mu\text{A}$ $\text{VCS}(+) = 1\text{V}$ | |
| CB output Lo voltage | VCBL | — | — | 25 | mV | $\text{VCS}(+) = 0\text{V}$, $\text{RCB} = 10\text{k}\Omega$ | |
| CFB output Lo voltage | VCFBL | — | — | 100 | mV | $I_{osink} = 100\mu\text{A}$, HSP ON $\text{VCS}(+) = 0\text{V}$, $\text{VCB} = 0.1\text{V}$ | |
| CFB output typ voltage | VCFBtyp | 1.19 | 1.25 | 1.31 | V | $\text{VCS}(+) = 0\text{V}$, $\text{VCB} = 0\text{V}$ $\text{RfOP4} = 1\text{k}\Omega$, HSP ON | |
| OP1 input offset voltage | VioOP1 | — | — | (1) | mV | | 1 |
| CS(+) input bias current | libCS(+) | — | -20 | -30 | μA | $\text{VCS}(+) = 0\text{V}$, $\text{VCS}(-) = 0\text{V}$ | |
| CS(−) input bias current | libCS(−) | — | 0.2 | 1.0 | μA | $\text{VCS}(+) = 0\text{V}$, $\text{VCS}(-) = 0\text{V}$ | |
| Cin input bias current | libCin | — | 0.2 | 1.0 | μA | $\text{V}_{cin} = 0\text{V}$ | |
| OP4 input resistance | Rsin | 0.75 | 1.00 | 1.25 | $\text{k}\Omega$ | | 1, 2 |
| Open loop gain OP1–OP6 | Avo | (70) | 80 | — | dB | | 1 |
| Band width OP1–OP6 | BWCS | — | 700 | — | kHz | | 1 |
| OCL detector threshold voltage | VthOCL | 59.5 | 62.5 | 65.5 | mV | CS(+) terminal voltage sensing | |
| Light load detector threshold Hi voltage | VthHLL | (2.0) | 3.5 | (5.0) | mV | CS(+) terminal voltage sensing | 1 |
| Light load detector threshold Lo voltage | VthLLL | (1.0) | 2.5 | (4.0) | mV | CS(+) terminal voltage sensing | 1 |
| VthLL hysteresis | dVthLL | (0.5) | 1.0 | (1.5) | mV | | 1 |
| Reverse current detector threshold Hi voltage | VthRC | -6 | -12 | -18 | mV | CS(+) terminal voltage sensing | 3 |

Notes:

1. Design spec.
2. Temperature coefficient is 5400ppm/ $^\circ\text{C}$.
3. Only HA16341NT/FP.

- Hot swap

| Item | Symbol | Min | Typ | Max | Unit | Test Conditions | Note |
|--------------------------|--------|------|------|------|---------------|---|------|
| HSP ON threshold voltage | VthHSP | 1.14 | 1.19 | 1.23 | V | 95% typ of reference 1.25V | |
| HSP charge current | IcHSP | -7 | -10 | -13 | μA | $\text{VHSP} = 5\text{V}$, $\text{VEIN} = 2\text{V}$ | |
| HSP output Lo voltage | VOLHSP | — | 0.3 | 0.6 | V | $\text{VEIN} = 1\text{V}$, $I_{osink} = 50\text{mA}$ | |

Electrical Characteristics (cont.)

($T_a = 25^\circ\text{C}$, $V_{CC} = 12\text{V}$, $\text{PG1} = 3\text{V}$, $\text{Vtrig} = 0\text{V}$, $\text{VCS}(+) = 0\text{V}$, $\text{VCin} = 0\text{V}$, $\text{CCT} = 330\text{pF}$, $\text{GvOP1} = 26\text{dB}$, $\text{GvOP4} = 40\text{dB}$, $\text{RDB} = 1.8\text{k}\Omega$)

- Oscillator

| Item | Symbol | Min | Typ | Max | Unit | Test Conditions | Note |
|---|---------------------|------|---------|------|---------------|--|------------|
| Typical oscillating frequency | fosc typ | 180 | 200 | 220 | kHz | | $\pm 10\%$ |
| Maximum oscillating frequency | fosc max | 400 | — | — | kHz | | |
| Typical oscillating temperature stability | d _{fosc} | — | ± 5 | — | % | $-20^\circ\text{C} < T_a < 85^\circ\text{C}$ | 1 |
| CT charge current | I _{ci} | -135 | -169 | -203 | μA | | $\pm 20\%$ |
| CT discharge current | I _{cd} | 616 | 770 | 924 | μA | | $\pm 20\%$ |
| Upper trip point | V _{thCTH} | — | 3.4 | — | V | | 2 |
| Lower trip point | V _{thCTL} | — | 1.3 | — | V | | |
| Amplitude | d _{VCT} | — | 2.1 | — | V | | |
| Exit trigger V _{th} | V _{thtrig} | -0.3 | -0.5 | -0.7 | V | | |

Notes:

- Design spec.

2. In case of external trigger control, CCT should be changed from 330 pF to 430 pF.

At this synchronous and 430 pF CCT condition V_{thCTH} becomes about 2.9 V.

- V_{ref}

| Item | Symbol | Min | Typ | Max | Unit | Test Conditions | Note |
|-----------------------|-----------------------|-----|-----|-----|-----------------------|--|-----------|
| Reference voltage | V _{ref} | 4.9 | 5.0 | 5.1 | V | I _{osource} = 1mA | $\pm 2\%$ |
| Line regulation | V _{ref-line} | — | 5 | 20 | mV | I _{osource} = 1mA $12\text{V} < V_{CC} < 18\text{V}$ | |
| Load regulation | V _{ref-load} | — | 5 | 20 | mV | $0 < I_{osource} < 3\text{mA}$ | |
| Temperature stability | d _{Vref} | — | 80 | — | ppm/ $^\circ\text{C}$ | $-20^\circ\text{C} < T_a < 85^\circ\text{C}$ | 1 |

Note:

- Design spec.

- UVL

| Item | Symbol | Min | Typ | Max | Unit | Test Conditions | Note |
|----------------------|------------------|-----|------|------|------|-----------------|------|
| Hi threshold voltage | V _H | 9.5 | 10.0 | 10.5 | V | | |
| Lo threshold voltage | V _L | 8.5 | 9.0 | 9.5 | V | | |
| Hysteresis | d _{UVL} | 0.6 | 1.0 | 1.4 | V | | |

Electrical Characteristics (cont.)

($T_A = 25^\circ\text{C}$, $V_{CC} = 12\text{V}$, $PG1 = 3\text{V}$, $V_{trig} = 0\text{V}$, $V_{CS(+)} = 0\text{V}$, $VC_{in} = 0\text{V}$, $CCT = 330\text{pF}$, $G_{vOP1} = 26\text{dB}$, $G_{vOP4} = 40\text{dB}$, $R_{DB} = 1.8\text{k}\Omega$)

- PG1

| Item | Symbol | Min | Typ | Max | Unit | Test Conditions | Note |
|--------------------------|--------------|--------|------|--------|------------------|-----------------|------|
| PG1 threshold Hi voltage | V_{thHPG1} | 2.4 | 2.5 | 2.6 | V | | |
| PG1 threshold Lo voltage | V_{thLPG1} | 1.9 | 2.0 | 2.1 | V | | |
| Input impedance | R_{inPG1} | (37.5) | 50.0 | (62.5) | $\text{k}\Omega$ | | 1 |

Note: 1. Design spec.

- FAIL

| Item | Symbol | Min | Typ | Max | Unit | Test Conditions | Note |
|-------------------|----------------|-----|-----|-----|---------------|---------------------------|------|
| Leak current | $I_{leakFAIL}$ | — | — | -10 | μA | $V_{FAIL} = 5\text{V}$ | |
| Output Lo voltage | V_{OLFAIL} | — | — | 0.5 | V | $I_{osink} = 10\text{mA}$ | |

- Error amp.

| Item | Symbol | Min | Typ | Max | Unit | Test Conditions | Note |
|-------------------------|-----------------|-------|------|------|---------------|--|-------------|
| Input threshold voltage | V_{thEIN} | 1.23 | 1.25 | 1.27 | V | $V_{EOUT} = 1.25\text{V}$ | $\pm 1.6\%$ |
| Input bias current | I_{bEIN} | — | -0.2 | -2.0 | μA | $V_{EIN} = 2\text{V}$ | |
| Open loop gain | A_{vEA} | 60 | 80 | — | dB | | |
| Band width | B_{WEA} | (0.7) | 1.4 | — | MHz | | 1 |
| EOUT sink current | $I_{osinkEA}$ | 0.5 | 5.0 | — | mA | $V_{EIN} = 1.5\text{V}$, $E_{OUT} = 1.1\text{V}$ | |
| EOUT source current | $I_{osourceEA}$ | -100 | -250 | — | μA | $V_{EIN} = 1.0\text{V}$, $E_{OUT} = 5\text{V}$ | |
| EOUT clamp voltage | V_{OHEA} | 5.8 | 6.8 | 7.8 | V | $V_{EIN} = 1.0\text{V}$ | |
| EOUT Lo voltage | V_{OLEA} | — | — | 1.0 | V | $V_{EIN} = 1.5\text{V}$, $I_{osink} = 200\mu\text{A}$ | |

Note: 1. Design spec.

- PWM OUT

| Item | Symbol | Min | Typ | Max | Unit | Test Conditions | Note |
|-------------------|-------------|--------------|--------------|-----|------|--|------|
| Output Lo voltage | V_{OLPWM} | — | 0.2 | 0.4 | V | $I_{osink} = 100\text{mA}$ | |
| Output Hi voltage | V_{OHPWM} | $V_{CC}-0.4$ | $V_{CC}-0.2$ | — | V | $I_{osource} = 100\text{mA}$ | |
| Rise time | t_{rPWM} | 20 | 50 | 100 | ns | $C_L = 3300\text{pF}$ | |
| Fall time | t_{fPWM} | 20 | 50 | 100 | ns | $C_L = 3300\text{pF}$ | |
| Maximum duty | D_{max} | 58 | 65 | 72 | % | $V_{SS} = 4\text{V}$, $V_{EIN} = 1.0\text{V}$ | |
| Minimum duty | D_{min} | — | — | 0 | % | $V_{SS} = 4\text{V}$, $V_{EIN} = 1.5\text{V}$ | |

Note: 1. Design spec.

Electrical Characteristics (cont.)

($T_a = 25^\circ\text{C}$, $V_{CC} = 12\text{V}$, $\text{PG1} = 3\text{V}$, $\text{Vtrig} = 0\text{V}$, $\text{VCS}(+) = 0\text{V}$, $\text{VCin} = 0\text{V}$, $\text{CCT} = 330\text{pF}$, $\text{GvOP1} = 26\text{dB}$, $\text{GvOP4} = 40\text{dB}$, $\text{RDB} = 1.8\text{k}\Omega$)

- MR OUT

| Item | Symbol | Min | Typ | Max | Unit | Test Conditions | Note |
|-------------------|--------|--------------|--------------|-----|------|----------------------------------|------|
| Output Lo voltage | VOLMR | — | 0.2 | 0.4 | V | $\text{Iosink} = 100\text{mA}$ | |
| Output Hi voltage | VOHMR | $V_{CC}-0.4$ | $V_{CC}-0.2$ | — | V | $\text{Iosource} = 100\text{mA}$ | |
| Rise time | trMR | 20 | 50 | 100 | ns | $\text{CL} = 3300\text{pF}$ | |
| Fall time | tfMR | 20 | 50 | 100 | ns | $\text{CL} = 3300\text{pF}$ | |

- MF OUT

| Item | Symbol | Min | Typ | Max | Unit | Test Conditions | Note |
|-------------------|--------|--------------|--------------|-----|------|----------------------------------|------|
| Output Lo voltage | VOLMF | — | 0.2 | 0.4 | V | $\text{Iosink} = 200\text{mA}$ | |
| Output Hi voltage | VOHMF | $V_{CC}-0.4$ | $V_{CC}-0.2$ | — | V | $\text{Iosource} = 200\text{mA}$ | |
| Rise time | trMF | 20 | 50 | 100 | ns | $\text{CL} = 6000\text{pF}$ | |
| Fall time | tfMF | 20 | 50 | 100 | ns | $\text{CL} = 6000\text{pF}$ | |

- Dead band time

| Item | Symbol | Min | Typ | Max | Unit | Test Conditions | Note |
|--------------------------------|--------|-------|----------------|------|------|--|------|
| Dead band time1 | Td1typ | 0 | 50 | 100 | ns | $\text{RDB} = 1.8\text{k}\Omega$ | |
| Dead band time2 | Td2typ | 0 | 100 | 200 | ns | $\text{RDB} = 1.8\text{k}\Omega$ | |
| MR to MF delay time | t1 | (-20) | — | (50) | ns | $t1 = \text{MF off} - \text{MR on}$ | 1 |
| PWM to MR delay time | t2 | (-20) | — | (50) | ns | $t2 = \text{MR off} - \text{PWM off}$ | 1 |
| MR delay time | t3 | — | 1 | — | μs | $t3 = \text{CT low trip point} - \text{MR on}$ | 1 |
| Maximum Dead band adjust time1 | Tdadj1 | — | Td1typ +300 | — | ns | $\text{RDB} = 47\text{k}\Omega$ | 1 |
| Maximum Dead band adjust time2 | Tdadj2 | — | Td2typ +600 | — | ns | $\text{RDB} = 47\text{k}\Omega$ | 1 |

Note: 1. Design spec.

Measurement is 50% slice point.

Electrical Characteristics (cont.)

($T_a = 25^\circ\text{C}$, $V_{CC} = 12\text{V}$, $\text{PG1} = 3\text{V}$, $\text{Vtrig} = 0\text{V}$, $\text{VCS}(+) = 0\text{V}$, $\text{VCin} = 0\text{V}$, $\text{CCT} = 330\text{pF}$, $\text{GvOP1} = 26\text{dB}$, $\text{GvOP4} = 40\text{dB}$, $\text{RDB} = 1.8\text{k}\Omega$)

- SS

| Item | Symbol | Min | Typ | Max | Unit | Test Conditions | Note |
|-----------------|---------------|-----|-----|-----|---------------|---|------|
| SS sink current | Idss | 500 | — | — | μA | $\text{PG1} = 2\text{V}$, $\text{VSS} = 2\text{V}$ | |

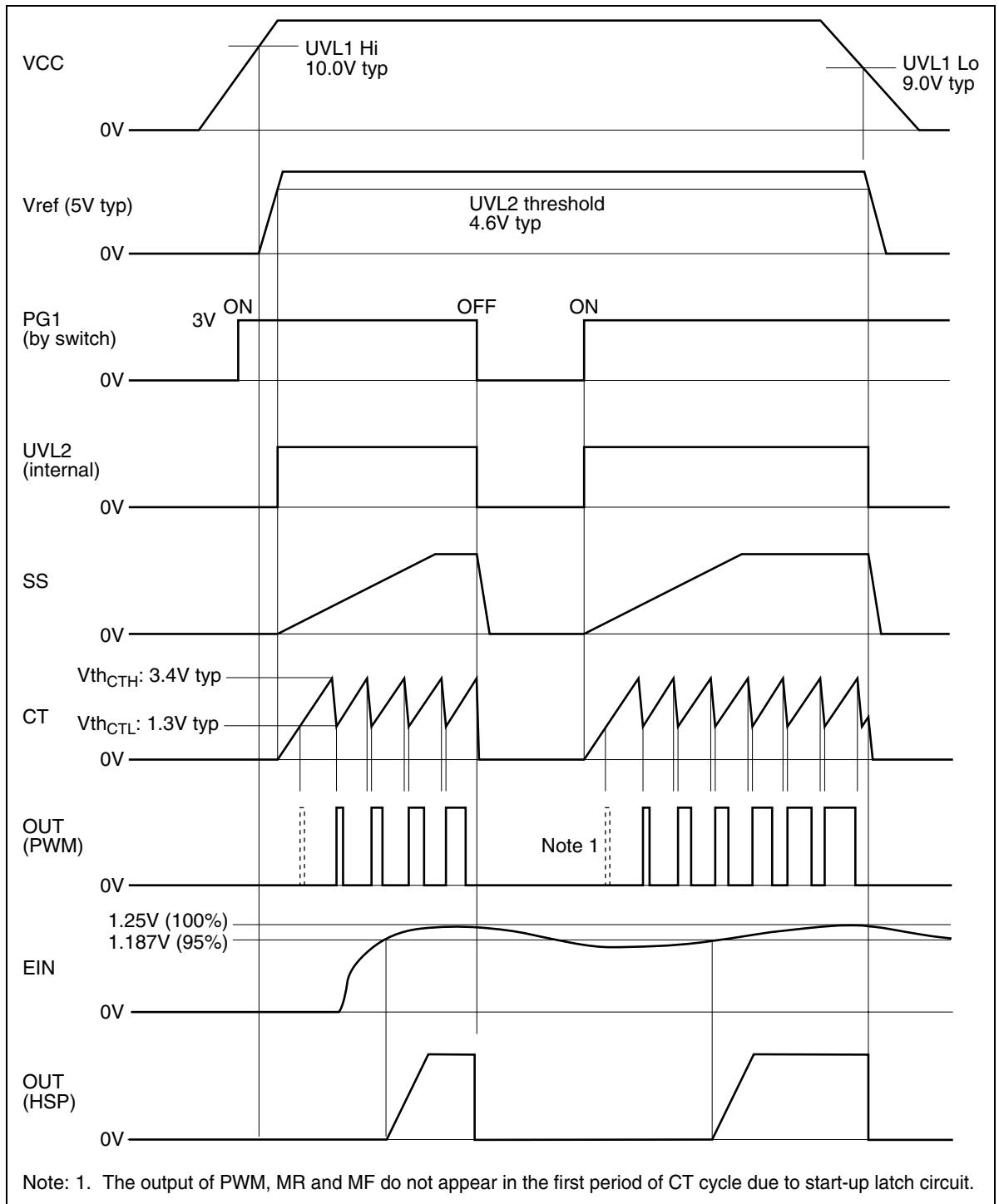
- OVP

| Item | Symbol | Min | Typ | Max | Unit | Test Conditions | Note |
|-------------------|---------------|-----|-----|-----|------|-----------------|------|
| OVP latch voltage | VOVP | 6.5 | 7.5 | 8.5 | V | | |

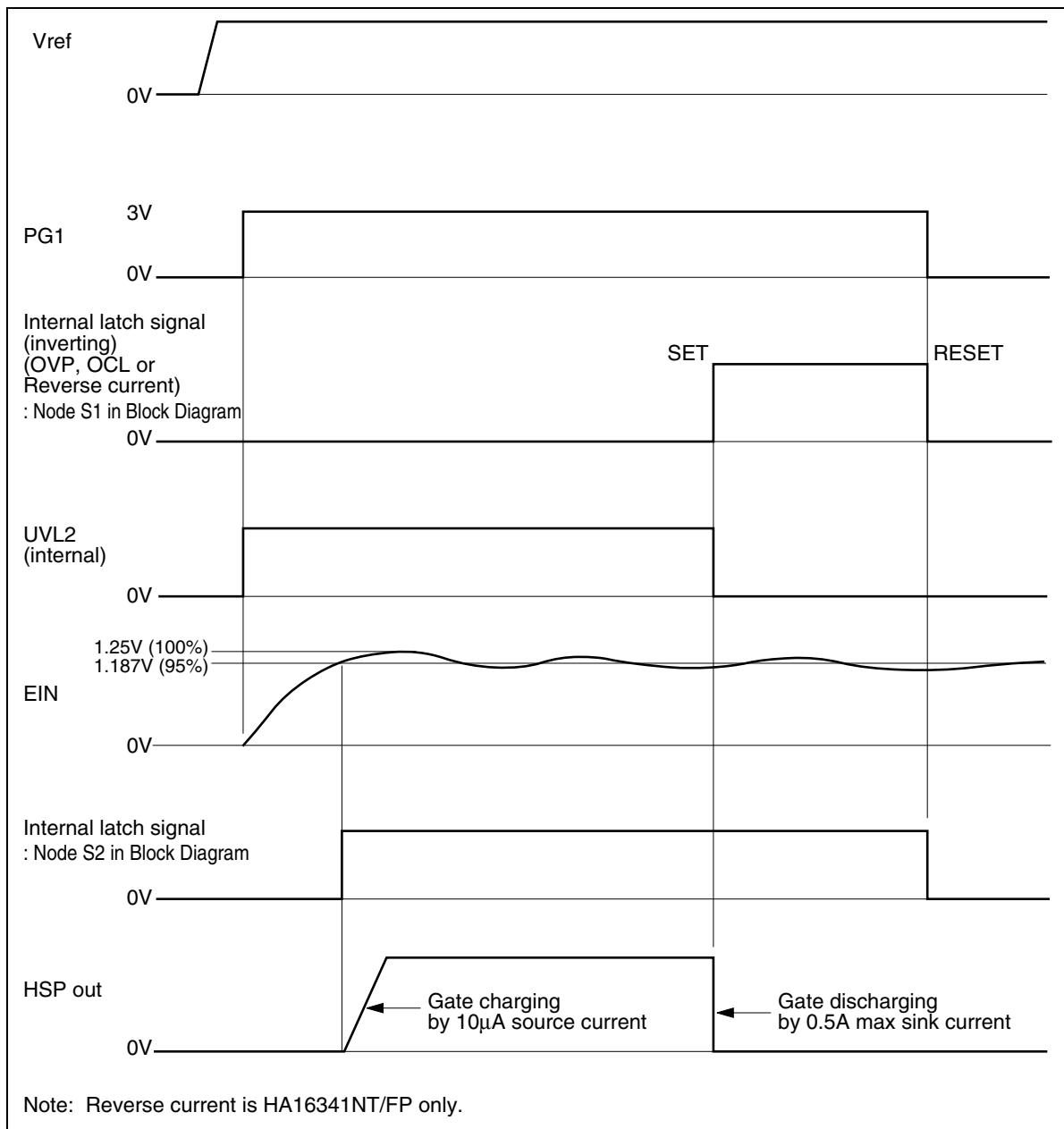
- Current consumption

| Item | Symbol | Min | Typ | Max | Unit | Test Conditions | Note |
|-------------------|----------------|-----|-----|-----|---------------|---|------|
| Operating current | ICC | 5.4 | 7.4 | 9.4 | mA | $\text{VCT} = 1\text{V}$ | |
| Standby current | ISTBY | — | 200 | 600 | μA | $\text{VCC} = 8\text{V}$, $\text{PG1} = 0\text{V}$ | |

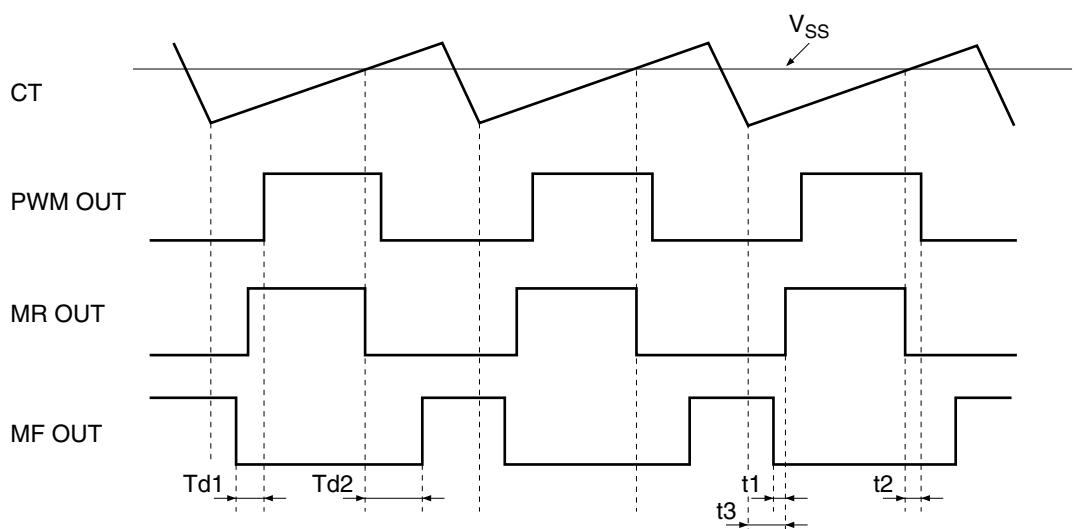
Timing Chart 1 (Total)



Timing Chart 2 (Hot Swap)

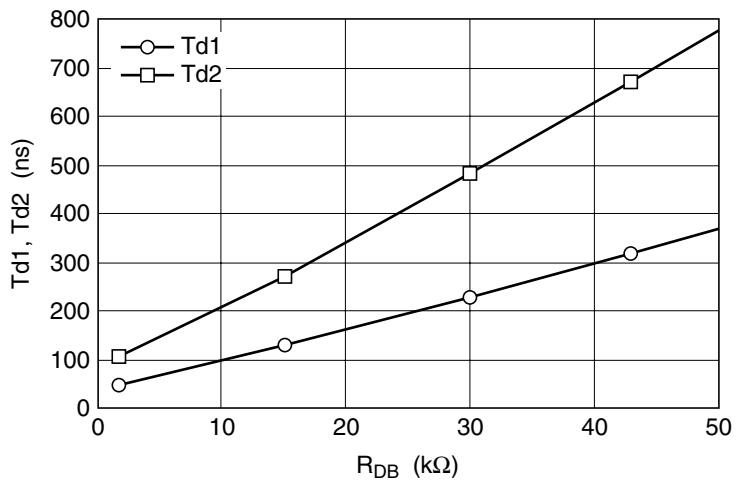
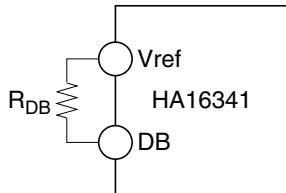


Timing Chart 3 (Dead Band Control)

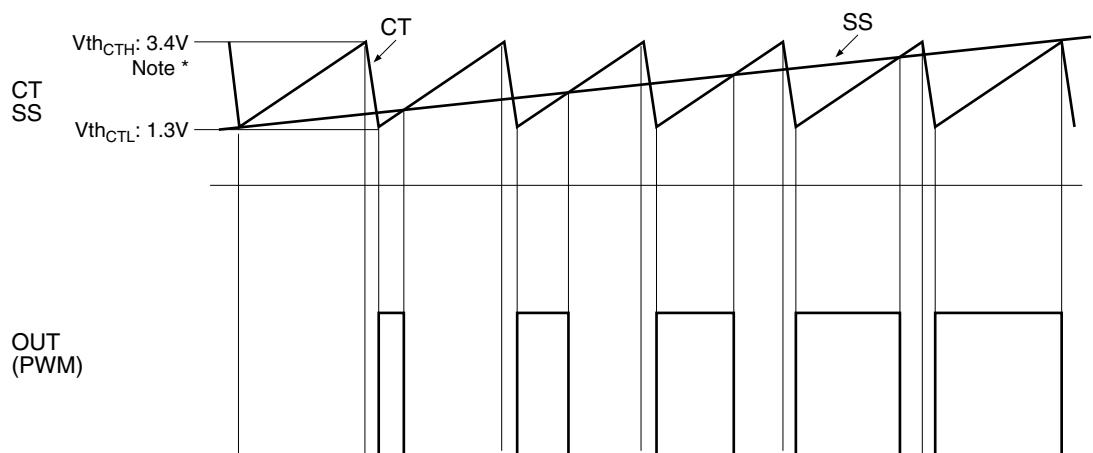


Note: V_{SS} determines maximum duty. This waveform example shows the case of EIN = Lo.

V_{SS} : Voltage of SS pin



Timing Chart 4 (Soft Start)



Note: Self-oscillation: $V_{th_{CTH}} = 3.4V$ typ
 Synchronized operation: $V_{th_{CTH}} = 2.9V$ typ

Case $V_{HSS} \geq V_{th_{CTH}}$
 Maximum duty would be the value specified in page 9.

Case $V_{HSS} < V_{th_{CTH}}$
 Maximum duty decrease to the corresponding value.

Please refer to formula 1 as design value of maximum duty.

Max duty = $(tss - 0.63\mu s - Td1) \times \text{Operating frequency}$ Formula 1

$$tss = \frac{C_{CT}}{I_{ci}} (V_{HSS} - V_{th_{CTL}})$$

I_{ci} : CT charge current
 C_{CT} : CT terminal capacitor
 $V_{th_{CTH}}$: CT upper trip point
 $V_{th_{CTL}}$: CT lower trip point

Select values R1, R2 and C1 for suitable maximum duty and SS time constant.

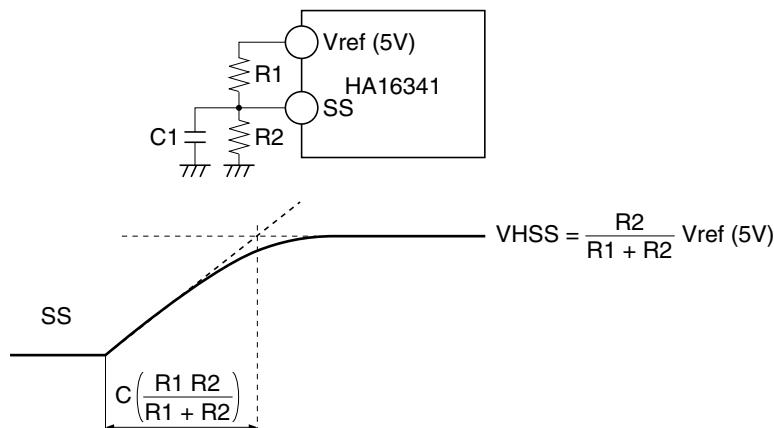
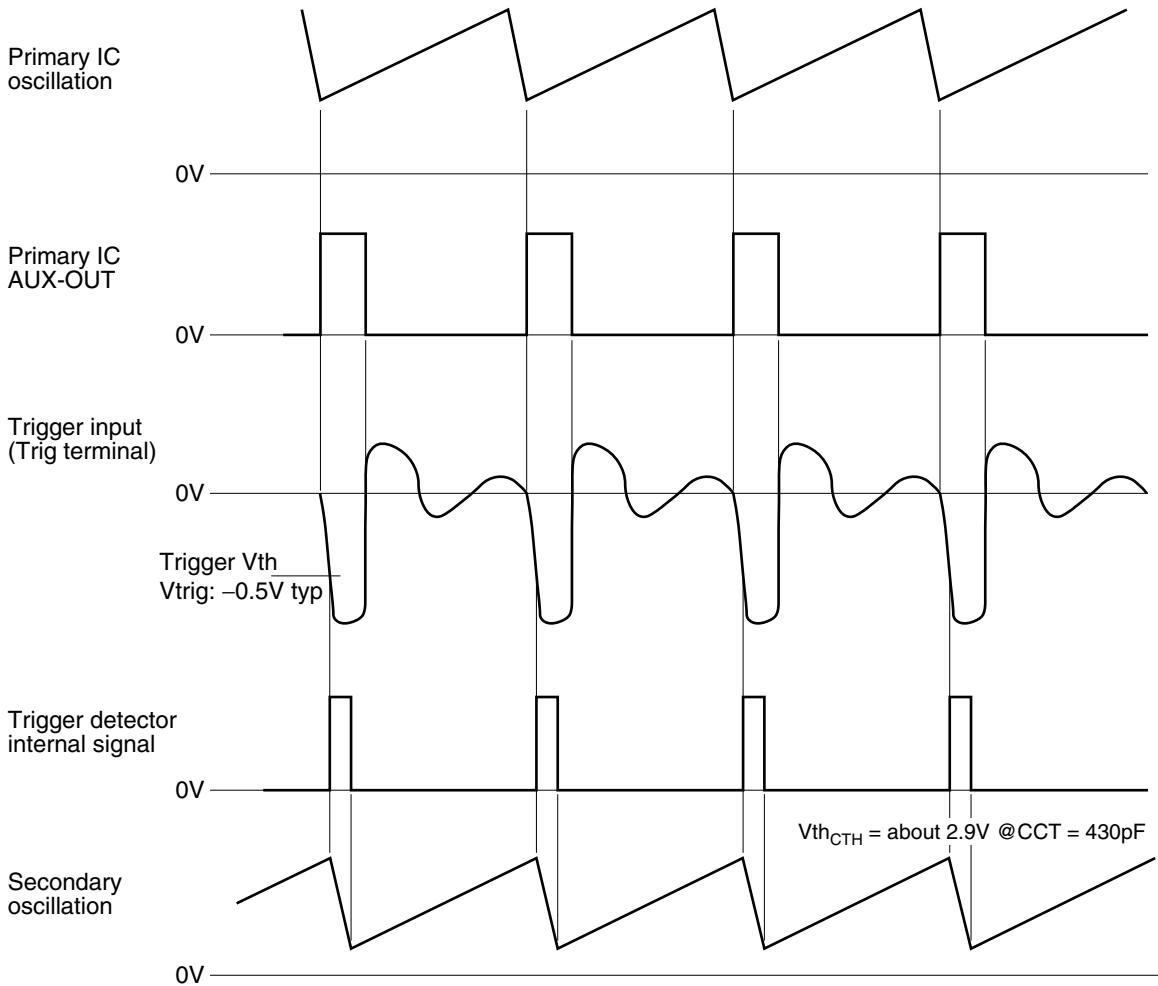


Figure A. SS Terminal Application

Timing Chart 5 (External Trigger Control)



This IC is triggered by negative pulse.

R1 and R2 must be calculated including internal impedance of $230k\Omega$.

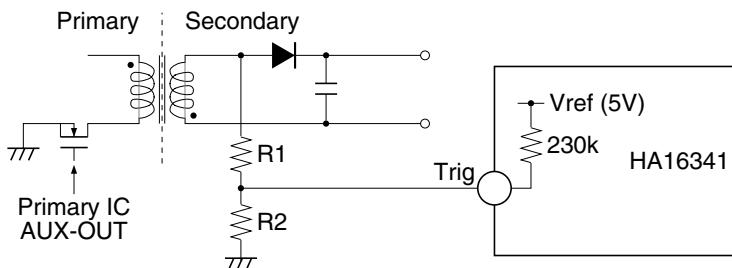
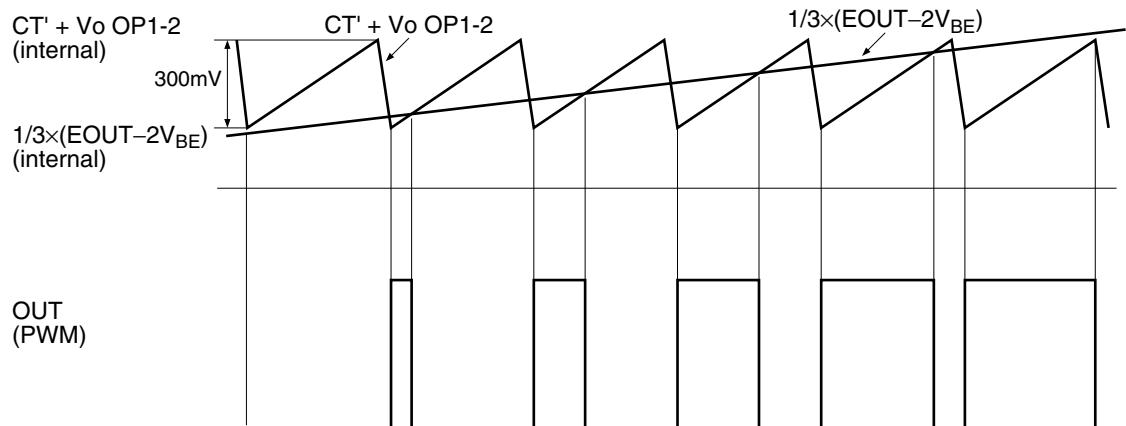


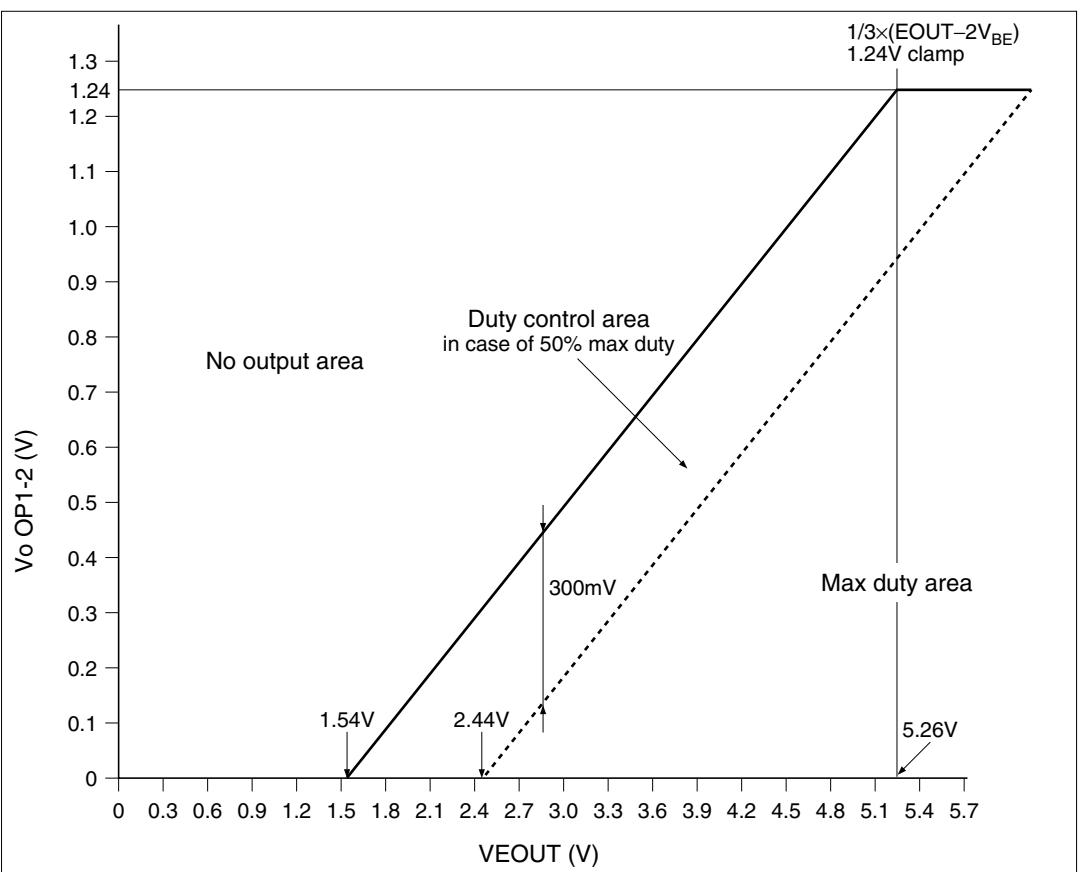
Figure B. External Trigger Application

Timing Chart 6 (Duty Control)

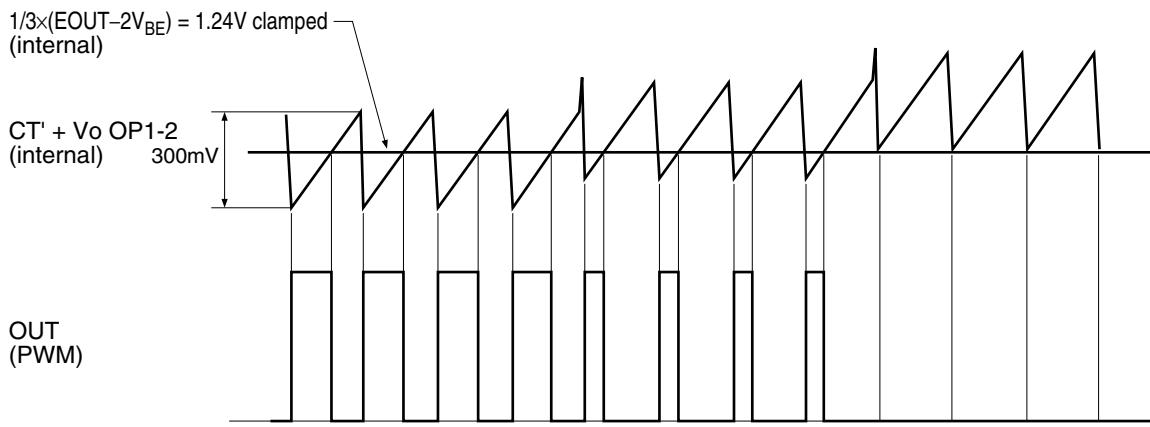


$$CT' = \frac{CT}{5.33}$$

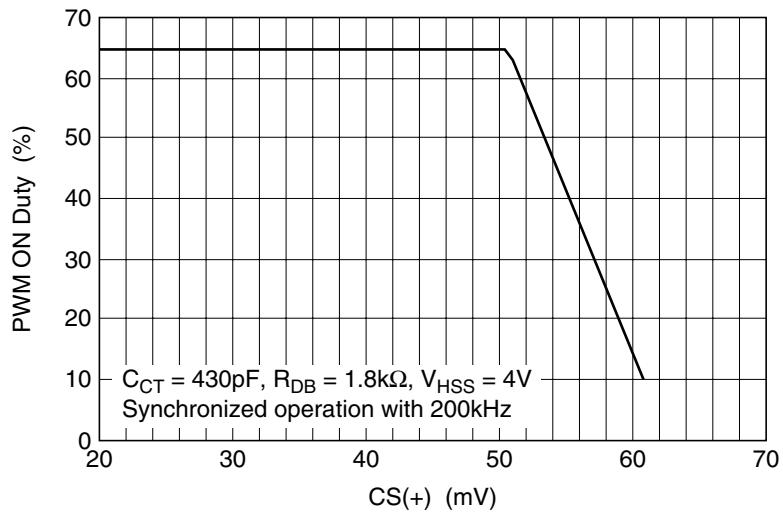
The amplitude of CT' is 300mV typ at synchronous operation with trigger frequency as 200kHz and C_{CT} = 430pF.



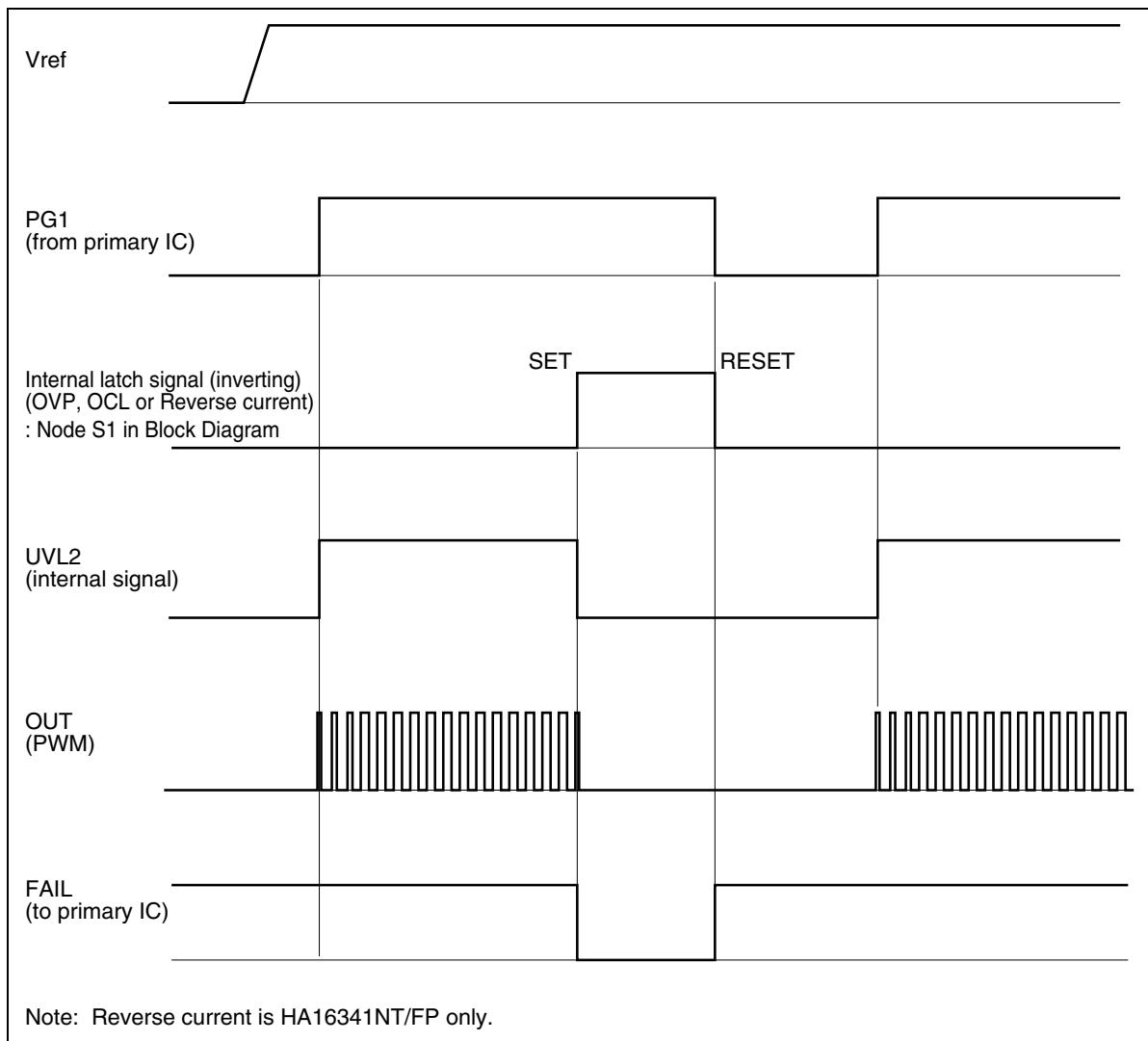
Timing Chart 7 (Current Limitting)



The amplitude of CT' is 300mV typ at synchronous operation with trigger frequency as 200kHz and C_{CT} = 430pF.

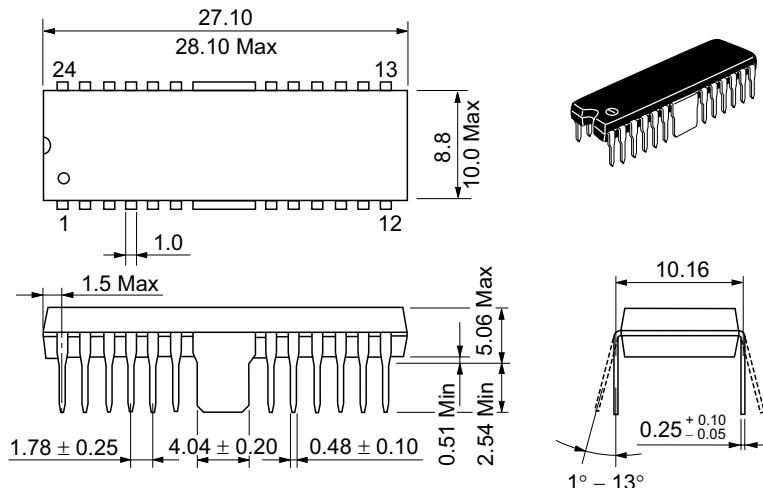


Timing Chart 8 (Interface with Primary Control IC)



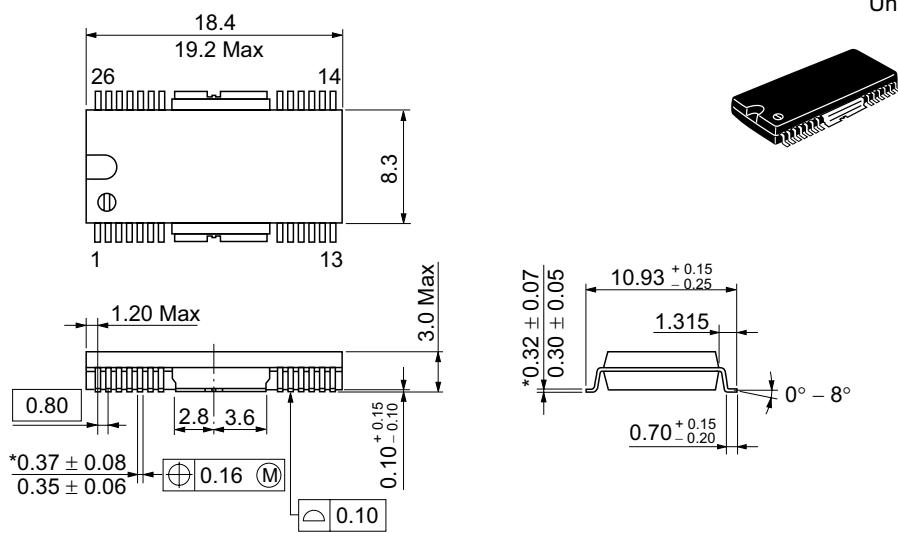
Package Dimensions

As of January, 2001
Unit: mm



| | |
|------------------------|---------|
| Hitachi Code | DP-24TS |
| JEDEC | — |
| EIAJ | — |
| Mass (reference value) | 2.04 g |

As of January, 2001
Unit: mm



| | |
|------------------------|---------|
| Hitachi Code | FP-26DT |
| JEDEC | — |
| EIAJ | — |
| Mass (reference value) | 0.98 g |

*Dimension including the plating thickness
Base material dimension

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